NSN 5962-01-254-6231

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View Online at https://aerobasegroup.com/nsn/5962-01-254-6231 **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.140 inches **Maximum Power Dissipation Rating:** 739.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** 3-state output and schottky and bipolar and programmable and monolithic **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Case Outline Source And Designator:** D-2 mil-m-38510 **Terminal Surface Treatment:** Gold **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:**

80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Precious Material And Location:

Terminal surfaces option gold

Precious Material:

Gold

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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